

Technical Data Sheet

3mm Silicon PIN Photodiode T-1

PD204-6B

Features

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Pb free
- The product itself will remain within RoHS compliant version.

Descriptions

- PD204-6B is a high speed and high sensitive PIN photodiode in a standard 3 Φ plastic package.
The device is matched to infrared emitting diode.



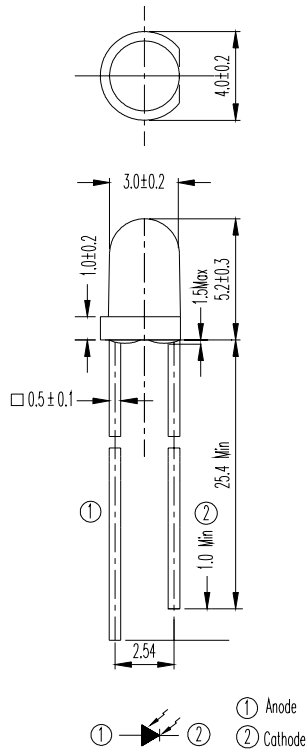
Applications

- Automatic door sensor
- Copier
- Game machine

Device Selection Guide

LED Part No.	Chip	Lens Color
	Material	
PD	Silicon	Water clear



Package Dimensions

- Notes:** 1.All dimensions are in millimeters
2.Tolerances unless dimensions ± 0.1 mm

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Rating	Units
Reverse Voltage	V_R	32	V
Operating Temperature	T_{opr}	$-25 \sim +85$	$^\circ\text{C}$
Storage Temperature	T_{stg}	$-40 \sim +85$	$^\circ\text{C}$
Soldering Temperature	T_{sol}	260	$^\circ\text{C}$
Power Dissipation at(or below) 25°C Free Air Temperature	P_c	150	mW

Notes: *1:Soldering time ≤ 5 seconds.

Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Rang Of Spectral Bandwidth	$\lambda_{0.5}$	---	840	---	1100	nm
Wavelength Of Peak Sensitivity	λ_p	---	---	940	---	nm
Open-Circuit Voltage	V_{OC}	Ee=5mW/cm ² $\lambda_p=940\text{nm}$	---	0.42	---	V
Short- Circuit Current	I_{SC}	Ee=1mW/cm ² $\lambda_p=940\text{nm}$	---	3.0	---	μA
Reverse Light Current	I_L	Ee=1mW/cm ² $\lambda_p=940\text{nm}$ $V_R=5\text{V}$	1.0	3.0	---	μA
Reverse Dark Current	I_D	Ee=0mW/cm ² $V_R=10\text{V}$	---	---	10	nA
Reverse Breakdown Voltage	B_{VR}	Ee=0mW/cm ² $I_R=100\mu\text{A}$	32	170	---	V
Total Capacitance	C_t	Ee=0mW/cm ² $V_R=5\text{V}$ $f=1\text{MHz}$	---	5	---	pF
Rise Time	t_r	$V_R=10\text{V}$ $R_L=1000\Omega$	---	6	---	nS
Fall Time	t_f		---	6	---	

Typical Electro-Optical Characteristics Curves

Fig.1 Power Dissipation vs.
Ambient Temperature

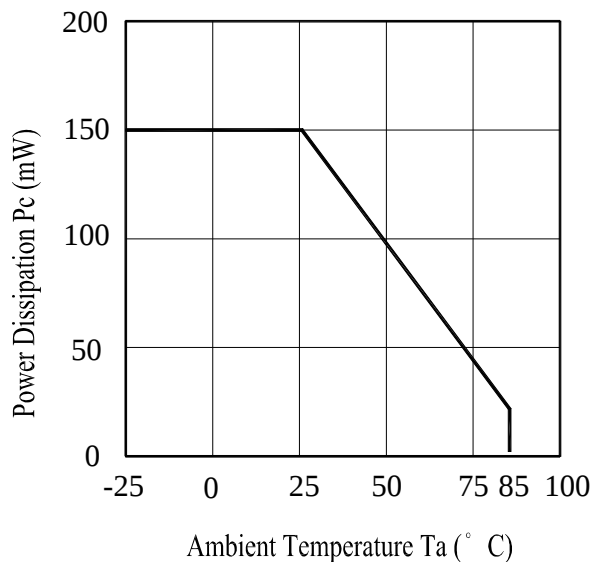


Fig.2 Spectral Sensitivity

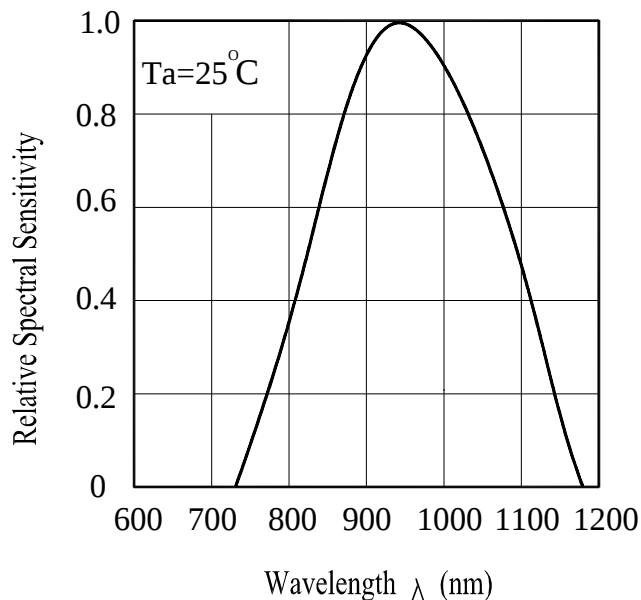


Fig.3 Dark Current vs.
Ambient Temperature

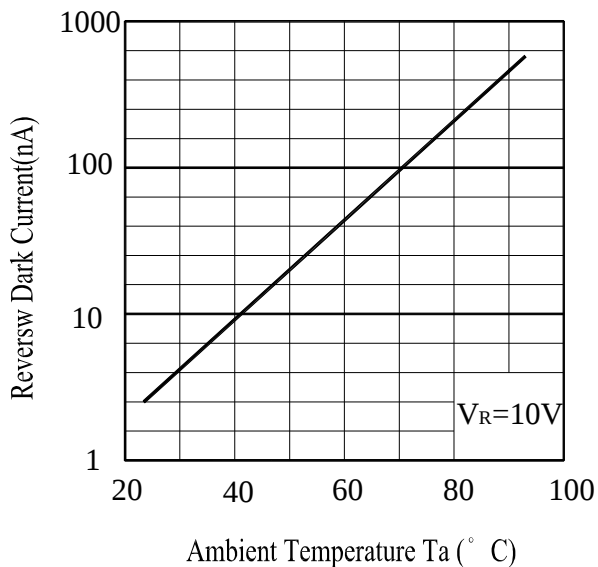
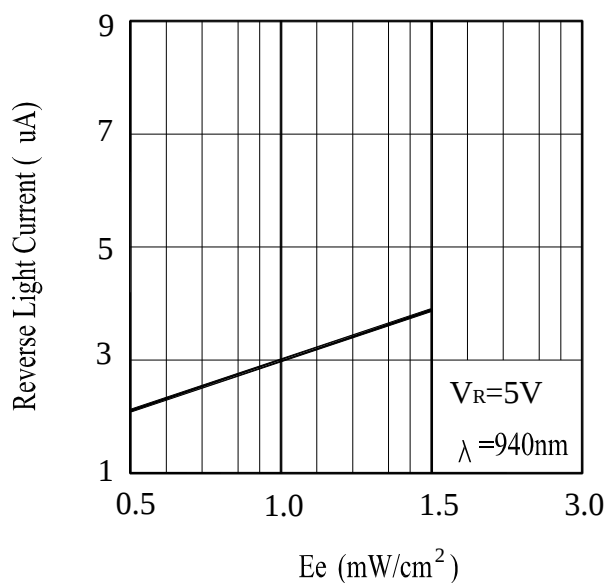


Fig. 4 Reverse Light Current vs.
 E_e



Typical Electro-Optical Characteristics Curves

Fig.5 Terminal Capacitance vs.

Reverse Voltage

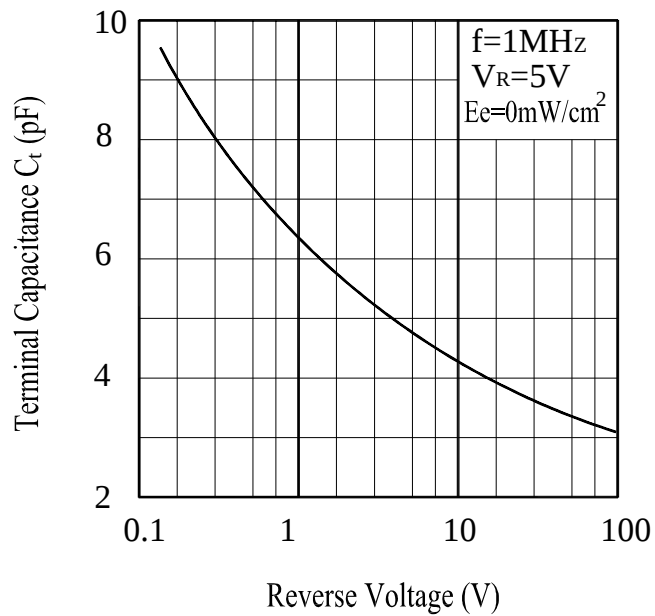
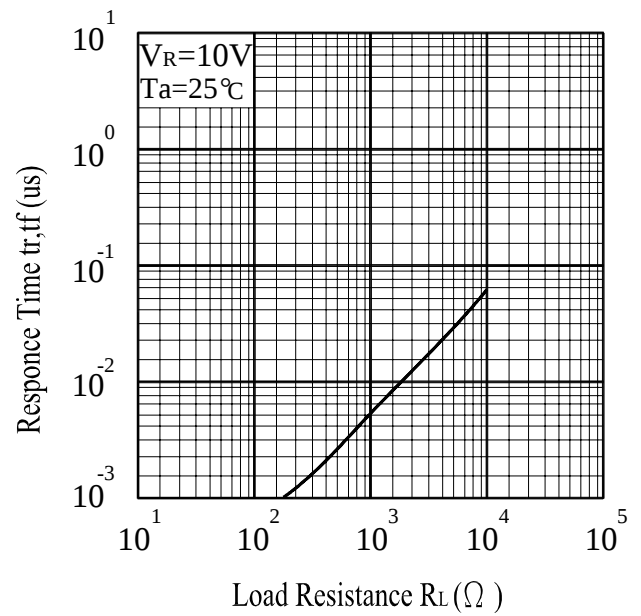


Fig.6 Response Time vs.

Load Resistance



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP. : $260^{\circ}\text{C} \pm 5^{\circ}\text{C}$	10secs	22pcs	$I_L \leq L \times 0.8$ L : Lower Specification Limit	0/1
2	Temperature Cycle	H : $+100^{\circ}\text{C}$ 15mins ↓ 5mins L : -40°C 15mins	300Cycles	22pcs		0/1
3	Thermal Shock	H : $+100^{\circ}\text{C}$ 5mins ↓ 10secs L : -10°C 5mins	300Cycles	22pcs		0/1
4	High Temperature Storage	TEMP. : $+100^{\circ}\text{C}$	1000hrs	22pcs		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000hrs	22pcs		0/1
6	DC Operating Life	$V_R = 5\text{V}$	1000hrs	22pcs		0/1
7	High Temperature/ High Humidity	85°C / 85% R.H	1000hrs	22pcs		0/1

Packing Quantity Specification

1.1000PCS/1Bag , 4Bags/1Box

2.10Boxes/1Carton

Label Form Specification

EVERLIGHT	
CPN:	
P/N:	
	RoHS
QTY:	PD204-6B
	CAT:
LOT NO:	HUE:
	REF:
MADE IN TAIWAN	

CPN: Customer's Production Number

P/N : Production Number

QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

MADE IN TAIWAN: Production Place